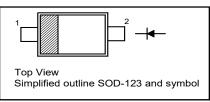
Silicon Epitaxial Planar Switching Diode

Features

Fast switching

PINNING

PIN	DESCRIPTION			
1	Cathode			
2	Anode			



Absolute Maximum Ratings ($T_a = 25$ °C)

Parameter		Symbol	Value	Unit
Peak Reverse Voltage		V_{RM}	100	V
Reverse Voltage	V_R	100	V	
Average Rectified Forward Current	$I_{F(AV)}$	200	mA	
Peak Forward Current		I _{FM}	300	mA
Non-repetitive Peak Forward Surge Current	at t = 1 s at t = 1 ms at t = 1 µs	I _{FSM}	0.5 1 4	А
Power Dissipation		P_{D}	400	mW
Operating Junction Temperature Range		T _j	- 65 to + 150	°C
Storage Temperature Range		T _{stg}	- 65 to + 150	℃

Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance from Junction to Ambient 1)	$R_{\theta JA}$	312	°C/W

¹⁾ Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.



1N4148W

Characteristics at $T_a = 25$ °C

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at I _R = 10 μA	V _{(BR)R}	100	-	V
Forward Voltage at $I_F = 1 \text{ mA}$ at $I_F = 10 \text{ mA}$ at $I_F = 50 \text{ mA}$ at $I_F = 150 \text{ mA}$	V _F	- - -	0.715 0.855 1 1.25	V
Peak Reverse Current at V_R = 100 V at V_R = 20 V at V_R = 100 V, T_J = 150°C at V_R = 25 V, T_J = 150°C	I _R	- - -	1 25 50 30	μΑ nA μΑ μΑ
Total Capacitance at $V_R = 0 V$, $f = 1 MHz$	Ст	-	2	pF
Reverse Recovery Time at I_F = 10 mA , I_{rr} = 0.1 × I_R , V_R = 6 V, R_L = 100 Ω	t _{rr}	-	4	ns



0

0

25

50

Electrical Characteristics Curves

Fig 1. Power Derating Curve

Fig 2. Total Capacitance vs. Reverse Voltage

Fig 3. Reverse Current vs. Reverse Voltage

T_a, Ambient Temperature(*C)

100

150

175

75

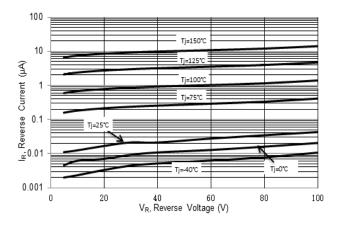
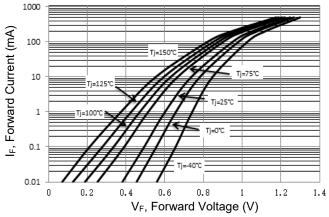


Fig 4. Forward Characteristics

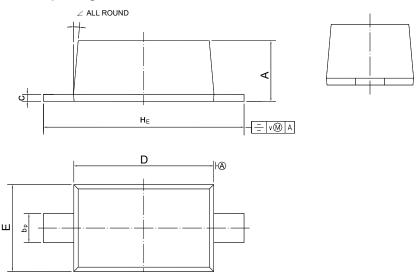
V_R, Reverse Voltage (V)



PACKAGE OUTLINE

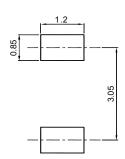
Plastic surface mounted package; 2 leads

SOD-123



UNIT	Α	bp	С	D	Е	HE	V	_
mm	1.15 1.05	0.6 0.5	0.135 0.100	2.7 2.6	1.65 1.55	3.85 3.55	0.2	5°

Recommended Soldering Footprint



Packing information

r deking information									
Package	Tape Width (mm)	Pitch		Reel	Size	Per Reel Packing Quantity			
		mm	(inch)	mm	(inch)	Fel Neel Facking Qualitity			
SOD-123	8	4 ± 0.1	0.157 ± 0.004	178	7	3,000			

Marking information

" W1 " = Part No.

" III " = Cathode line

Font type: Arial



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